

ME597/PHYS57000

Fall Semester 2009

Lecture 04

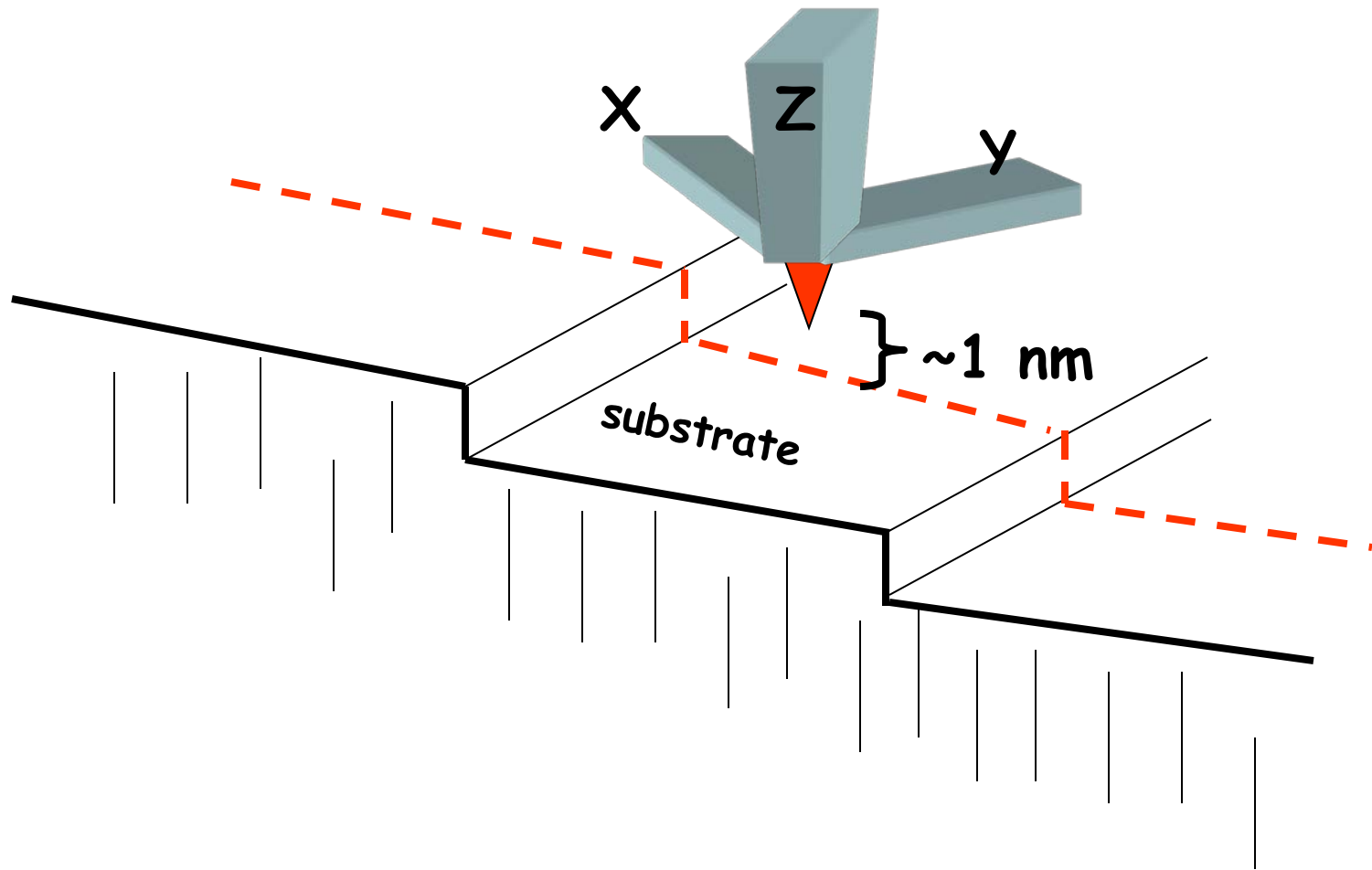
Early Successes

How to Make an STM

Suggested Reading: G. Binnig, H. Rohrer, Ch. Gerber, E. Weibel, "7x7 Reconstruction of Si(111) Resolved in Real Space", Phys. Rev. Lett. **50**, 120 (1983)

If gap is controllable, then hold gap at a fixed  $d$  so that  $e^{-2\alpha d} = \text{constant}$ , then

$$I(x, y) \propto e\Delta V \rho(z=0, x, y; E_F)$$



# What might effect LDOS?

- Surface
  - atom positions
  - step edges, terraces
  - reconstruction - position of atoms
- Grain Boundaries
- Adsorbates
- Impurities
- Anti-site Defects
- Dislocations
- Vacancies
- Interstitials
- etc. etc.

## A Few Early Successes

- Si(111) 7x7
- HOPG
- GaAS

# The Si(111) story

The Si(111) reconstruction was first reported in 1959 by R. Schlier and H. Farnsworth, J. Chem. Phys. **30**, 917 (1959).

Equilibrium surface structure (lowest energy arrangement) after annealing under UHV.

After the Si(111) reconstruction was discovered, there were ~20 papers written per year for 25 years, i.e. ~500 publications, attempting to conclusively identify the nature of the reconstruction.

The exact reconstruction was finally solved in a few days in 1982 using the STM. The STM data clearly showed a (7x7) unit cell bounded by minima corresponding to empty adatom positions and maxima corresponding to the presence of adatoms

**$7 \times 7$  Reconstruction on Si(111) Resolved in Real Space**

G. Binnig, H. Rohrer, Ch. Gerber, and E. Weibel

*IBM Zurich Research Laboratory, 8803 Rüschlikon-ZH, Switzerland*

(Received 17 November 1982)

The  $7 \times 7$  reconstruction on Si(111) was observed in real space by scanning tunneling microscopy. The experiment strongly favors a modified adatom model with 12 adatoms per unit cell and an inhomogeneously relaxed underlying top layer.

PACS numbers: 68.20.+t, 73.40.Gk

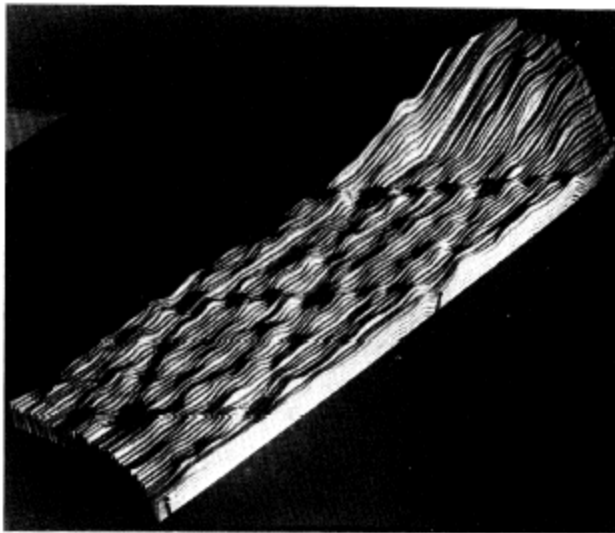


FIG. 1. Relief of two complete  $7 \times 7$  unit cells, with nine minima and twelve maxima each, taken at  $300^\circ\text{C}$ . Heights are enhanced by 55%; the hill at the right grows to a maximal height of  $15 \text{ \AA}$ . The  $[\bar{2}11]$  direction points from right to left, along the long diagonal.

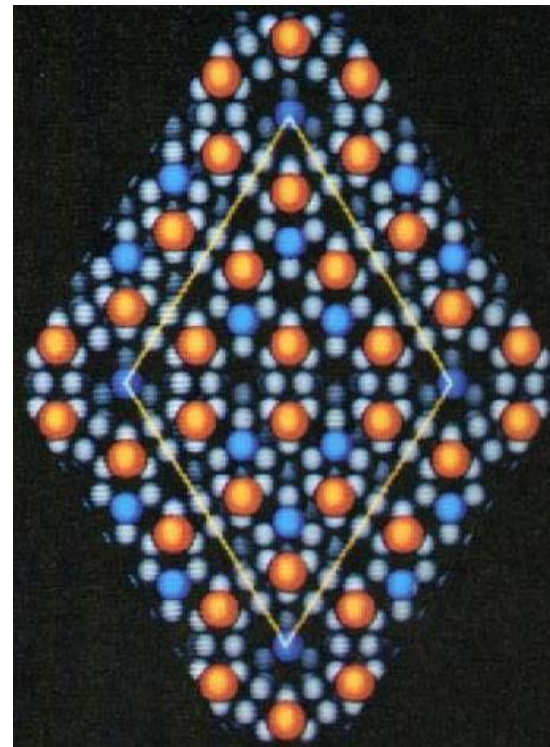
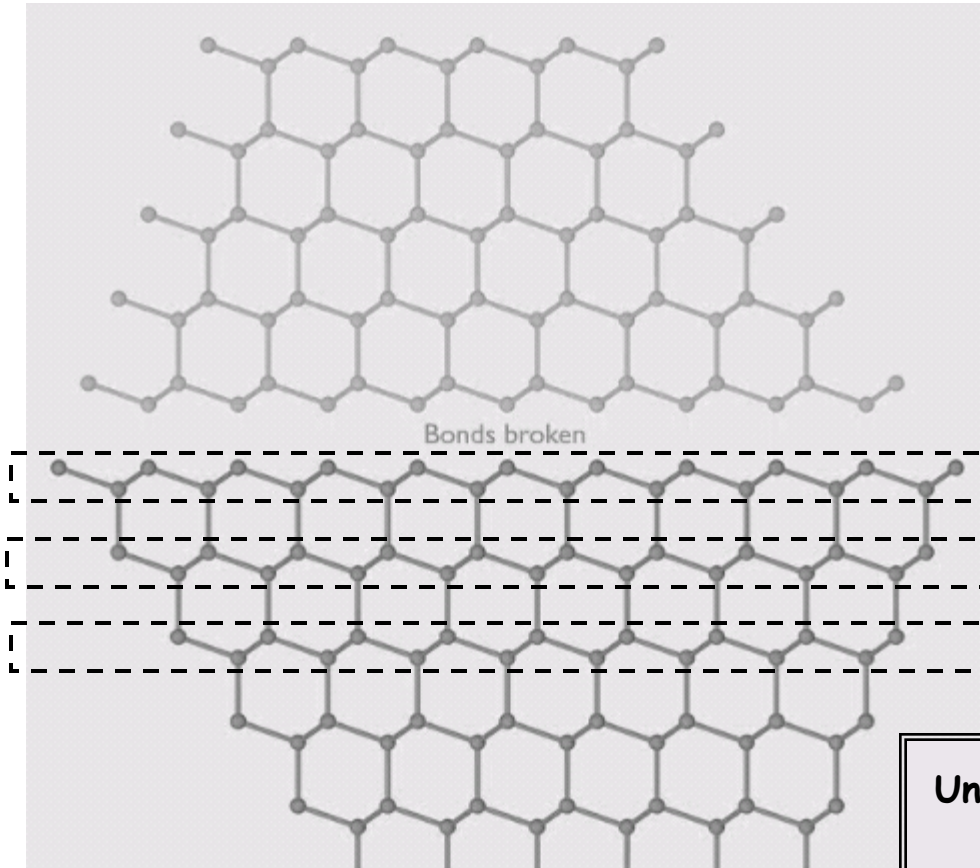


Figure from R.M. Tromp, IBM

# Some Details



1<sup>st</sup> bilayer



Si(111) surface

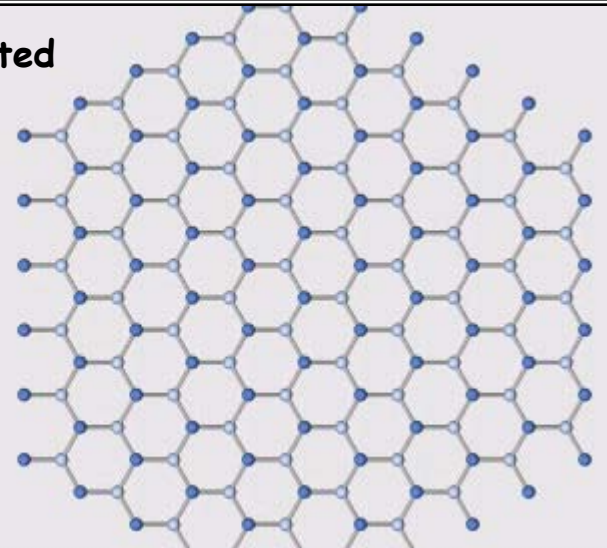
1<sup>st</sup> bilayer

2<sup>nd</sup> bilayer

3<sup>rd</sup> bilayer

Top view of 1<sup>st</sup> bilayer

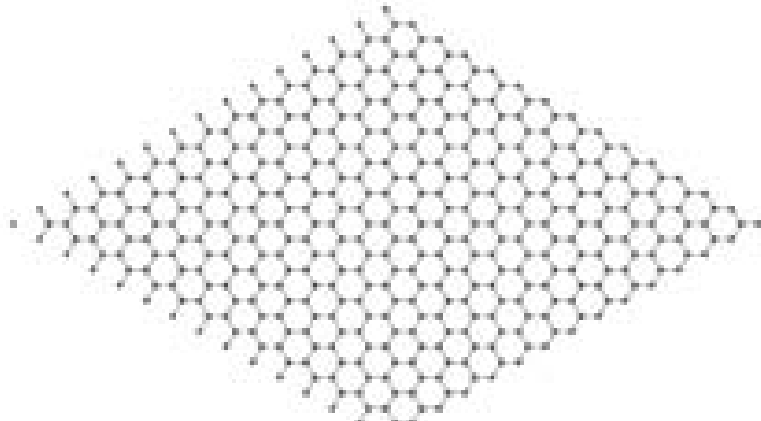
Unreconstructed surface



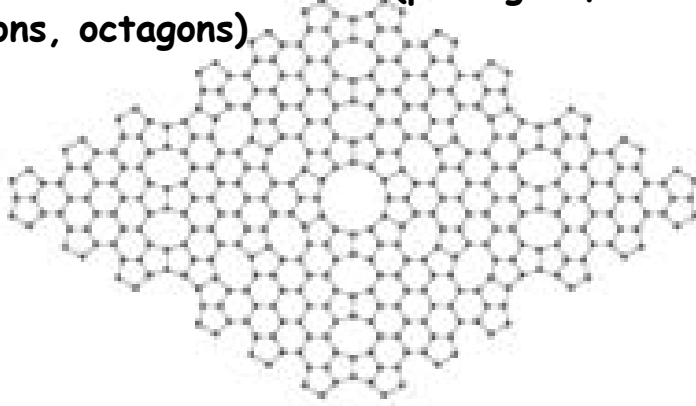
For animation by Yan Liang, see:  
<http://www.vimeo.com/1086112>

# Comparison

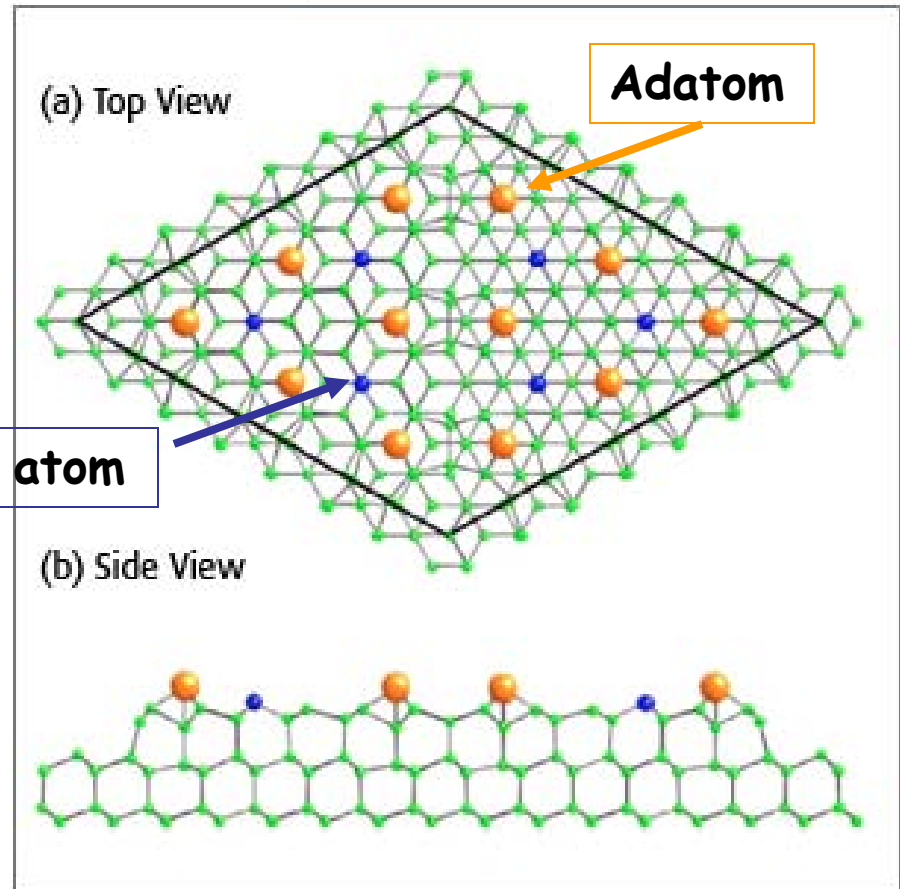
Unreconstructed 7x7 surface (all hexagons)



Reconstructed 7x7 surface (pentagons, hexagons, octagons)



From Omicron Web site:



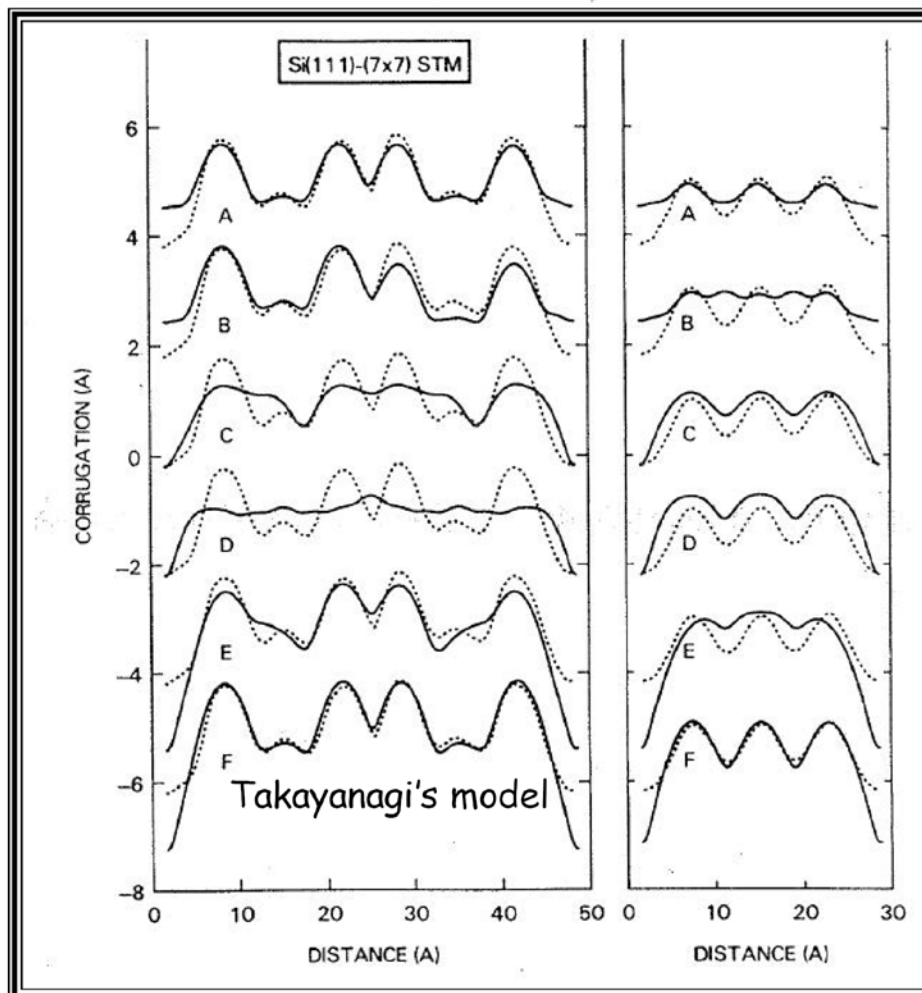


### Atomic and electronic contributions to Si(111)-(7x7) scanning-tunneling-microscopy images

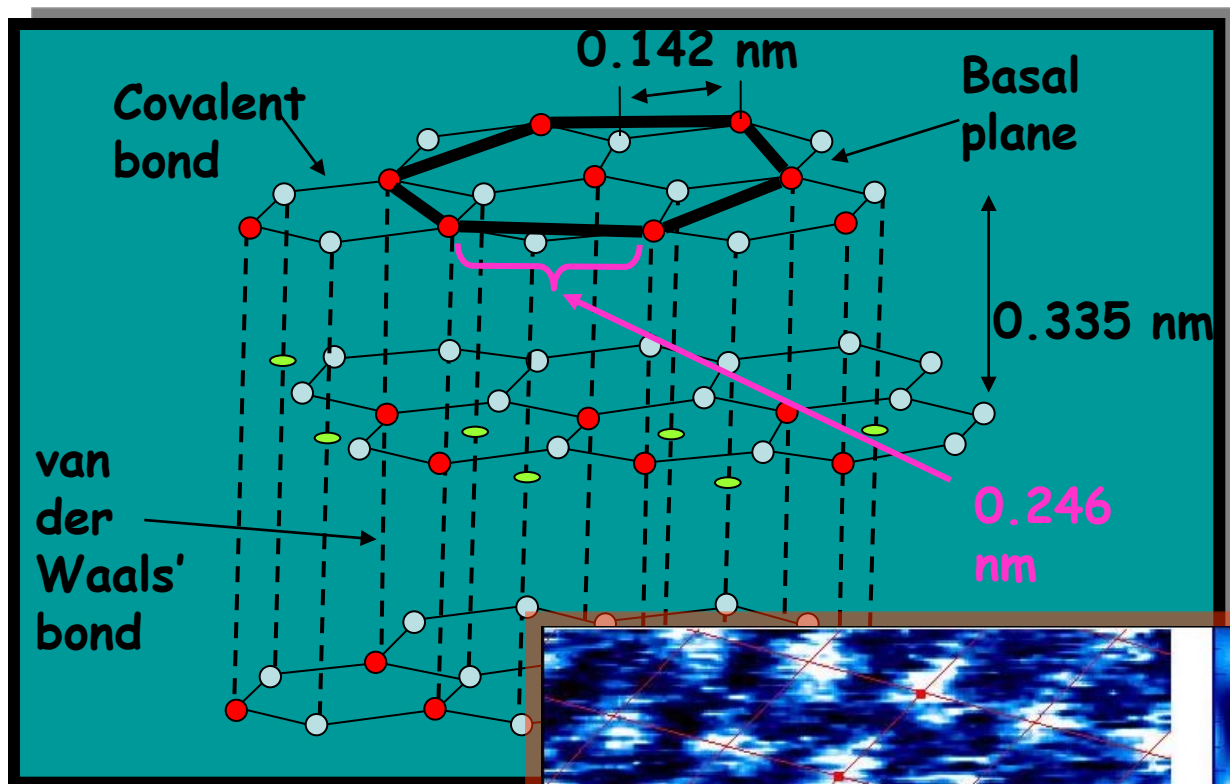
R. M. Tromp, R. J. Hamers, and J. E. Demuth

*IBM Thomas J. Watson Research Center, Yorktown Heights, New York 10598*

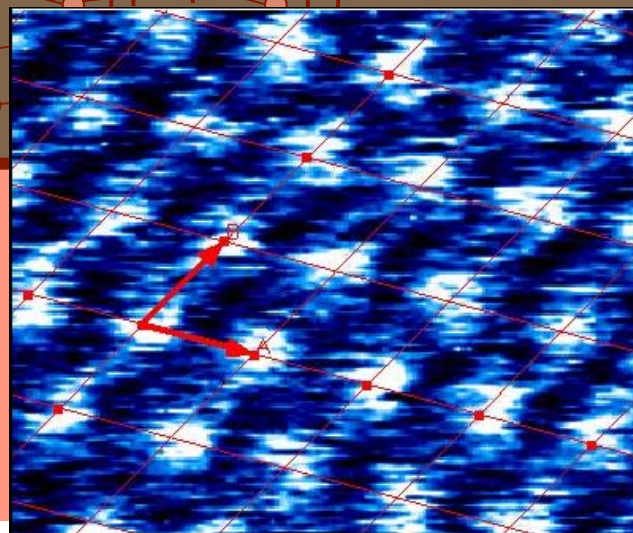
(Received 9 May 1986)



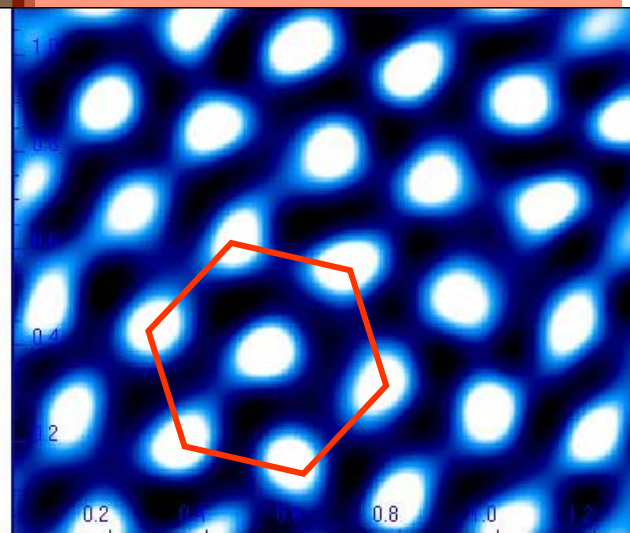
# A flat substrate: Highly Oriented Pyrolytic Graphite (HOPG)



(1.3 x 1.1 nm)

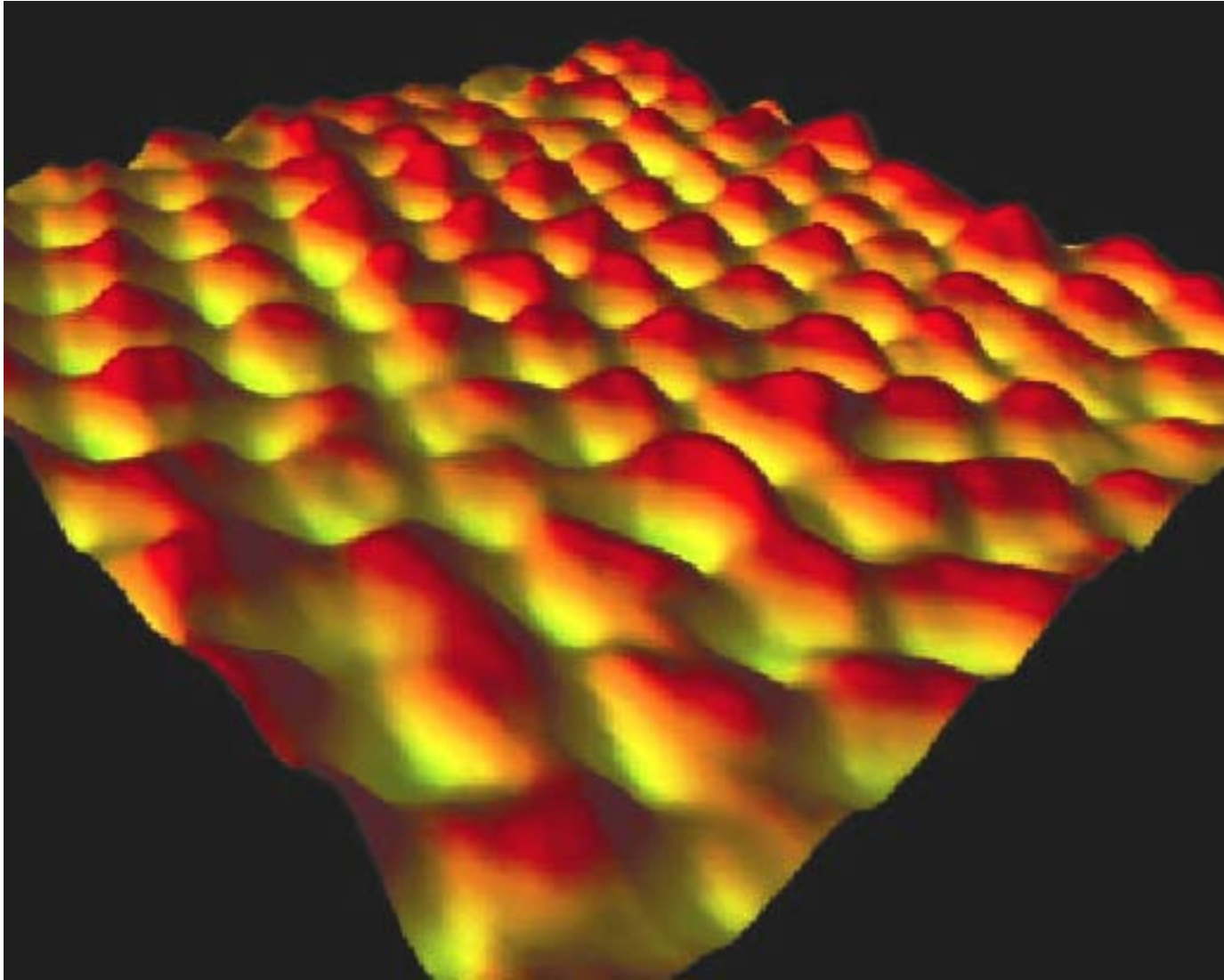


Raw data

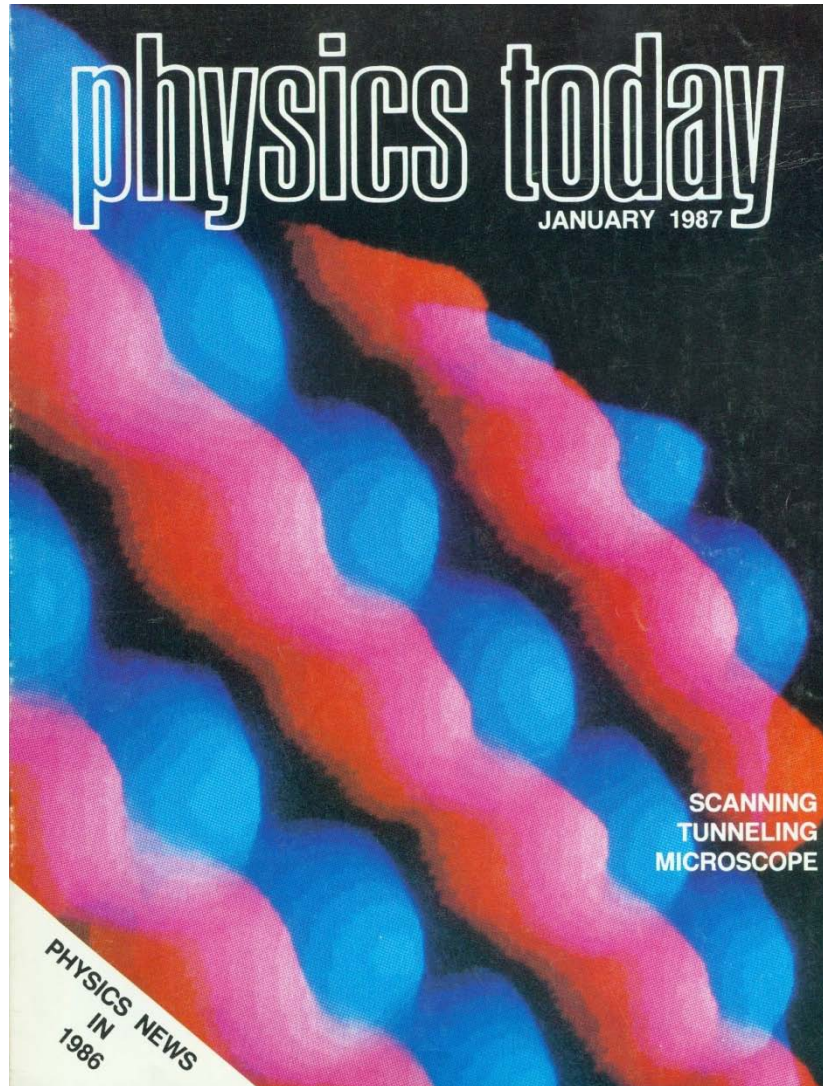


Fourier filtered image

# HOPG in 3-diemnsions

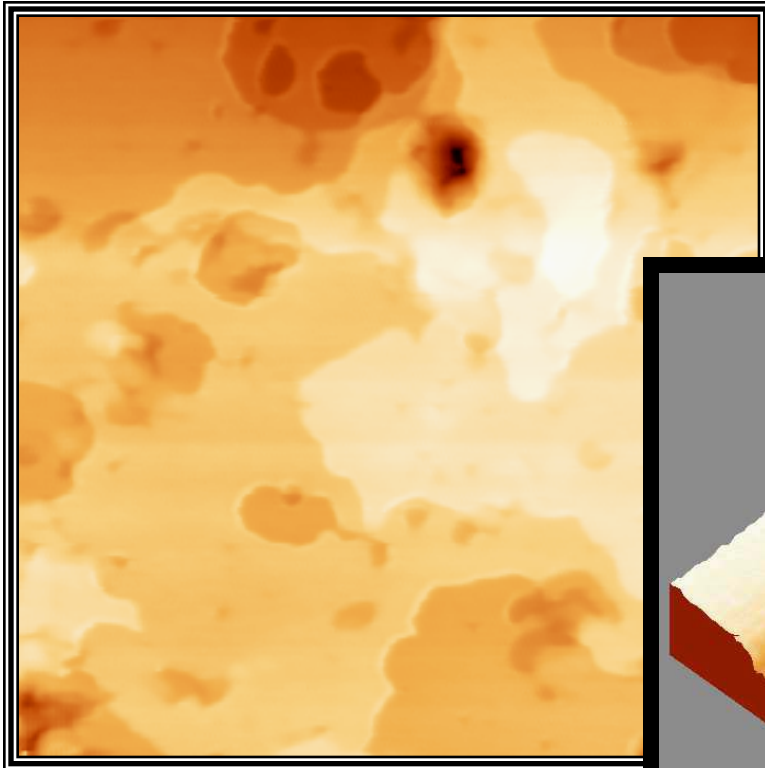


# STM of GaAs



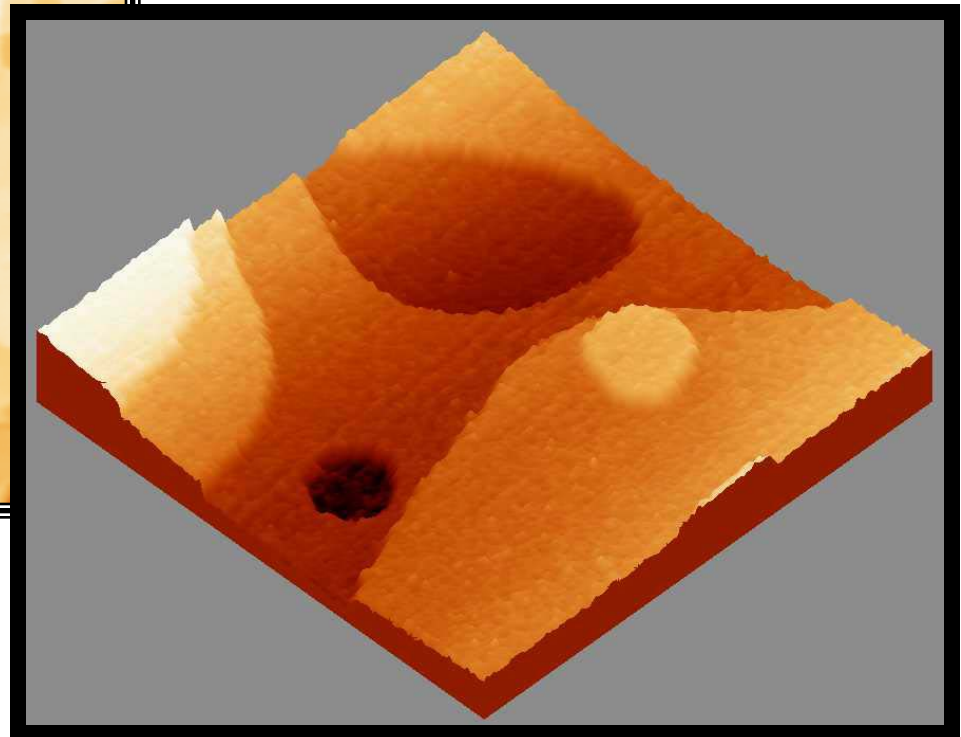
**Ga: red sites; As: blue sites**

# Imaging the surface of Au(111)



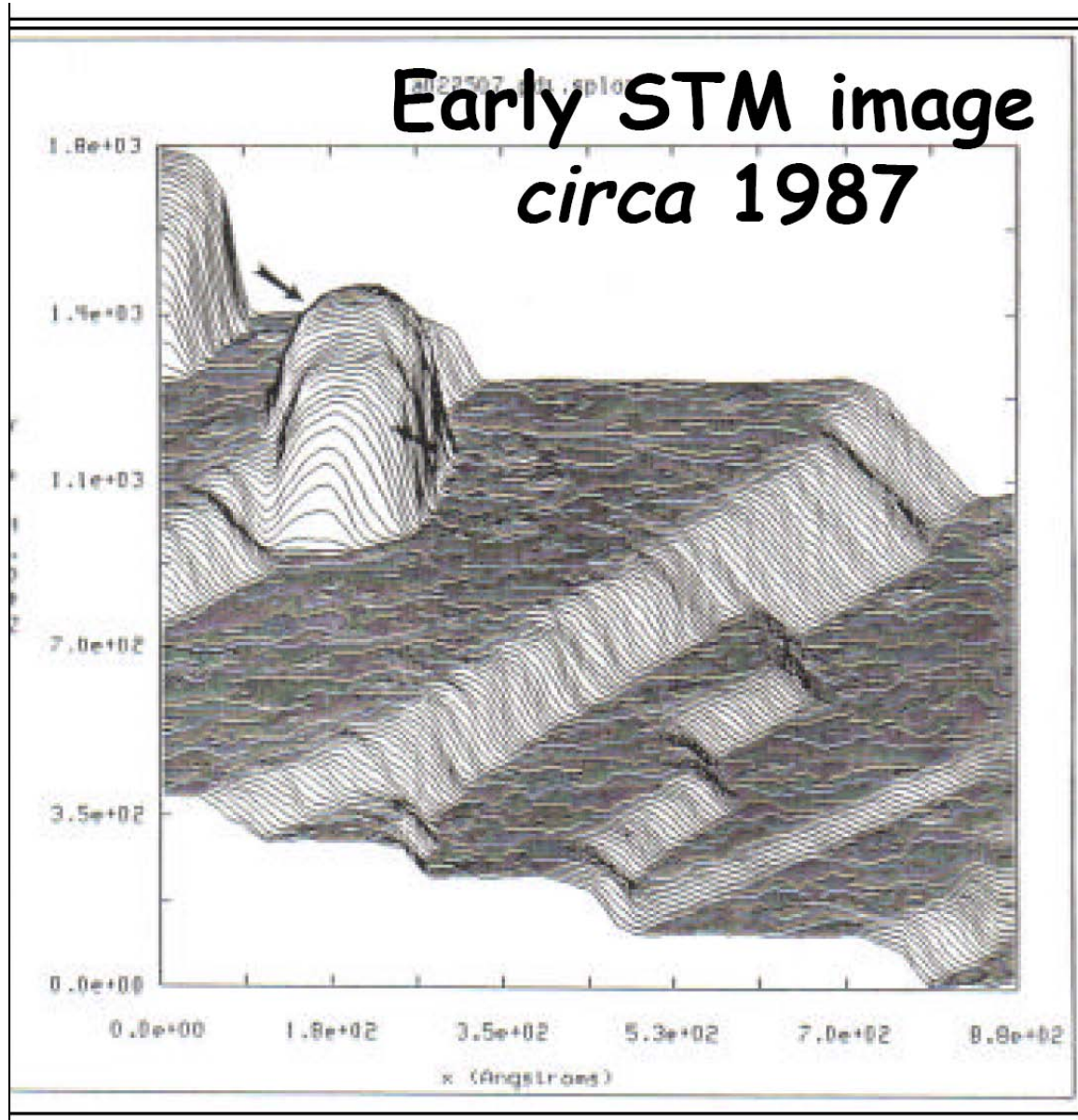
Top View

0.236 nm steps  
on Au(111)

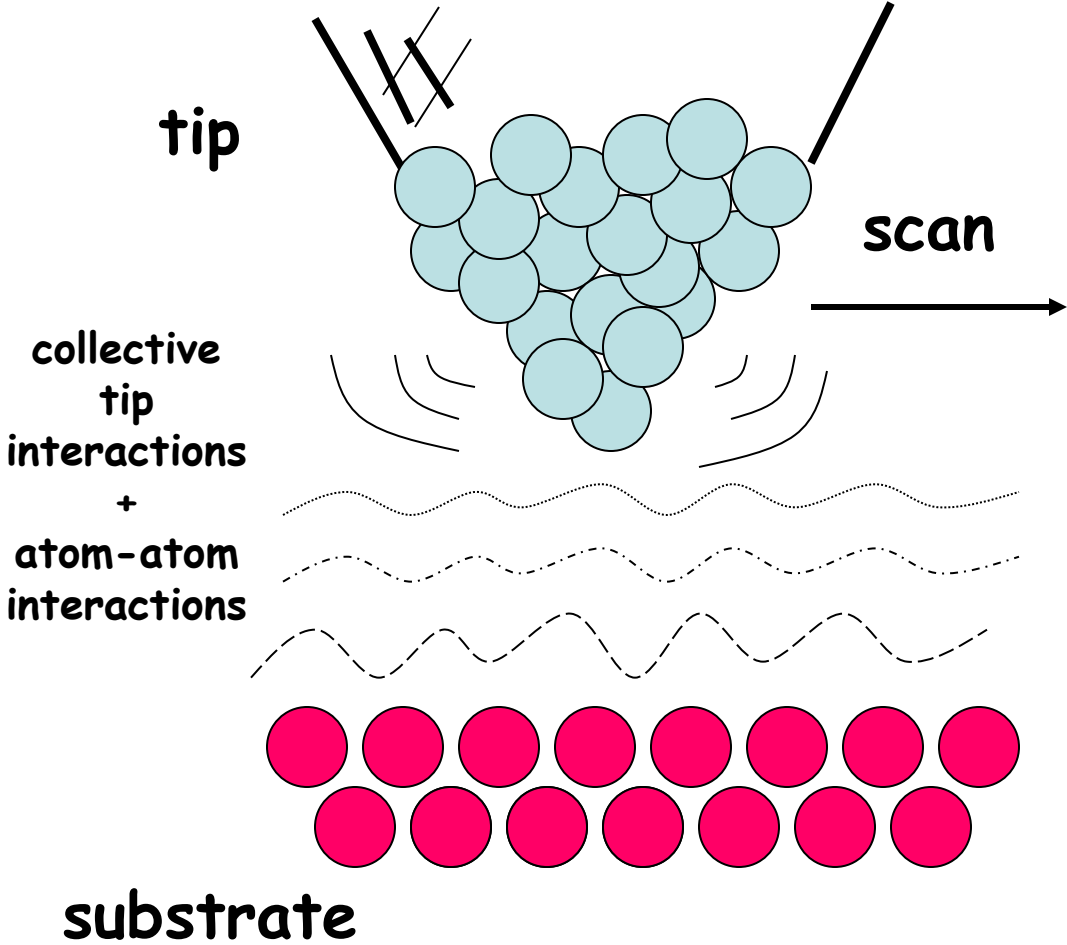


100 nm x 100 nm

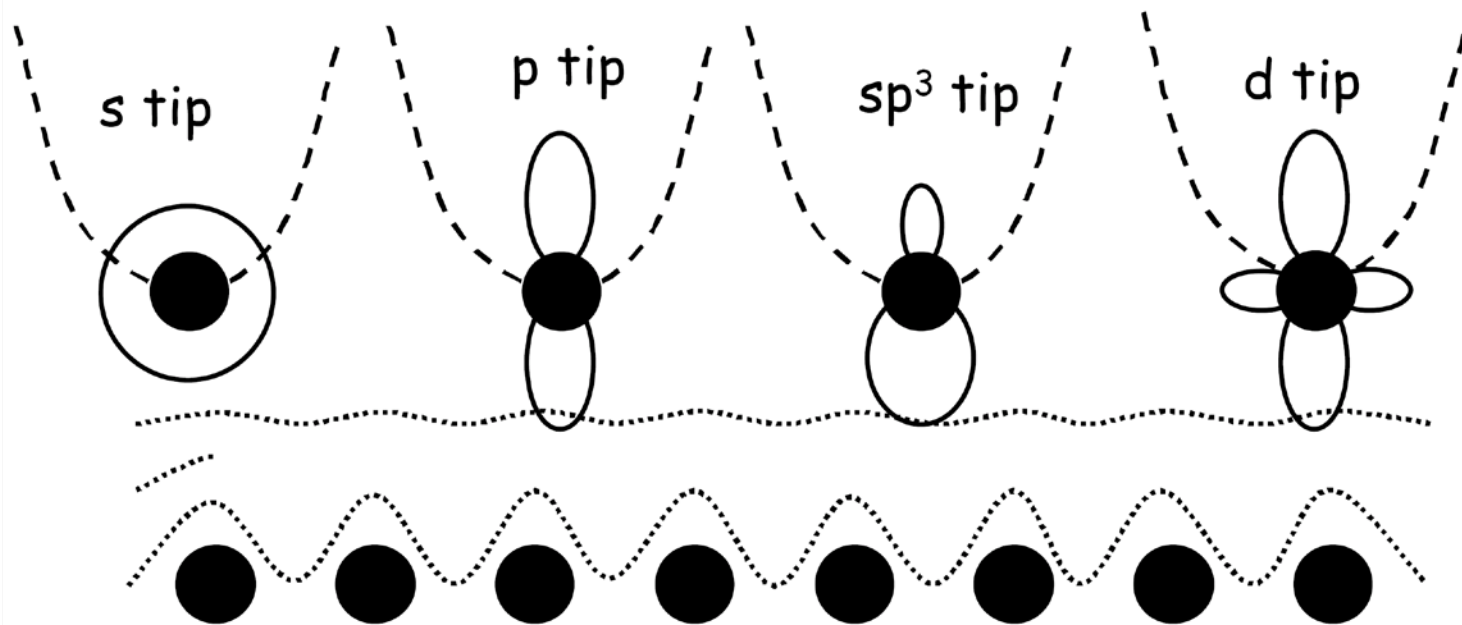
# Au nanoclusters on Au substrate



# Why it Works



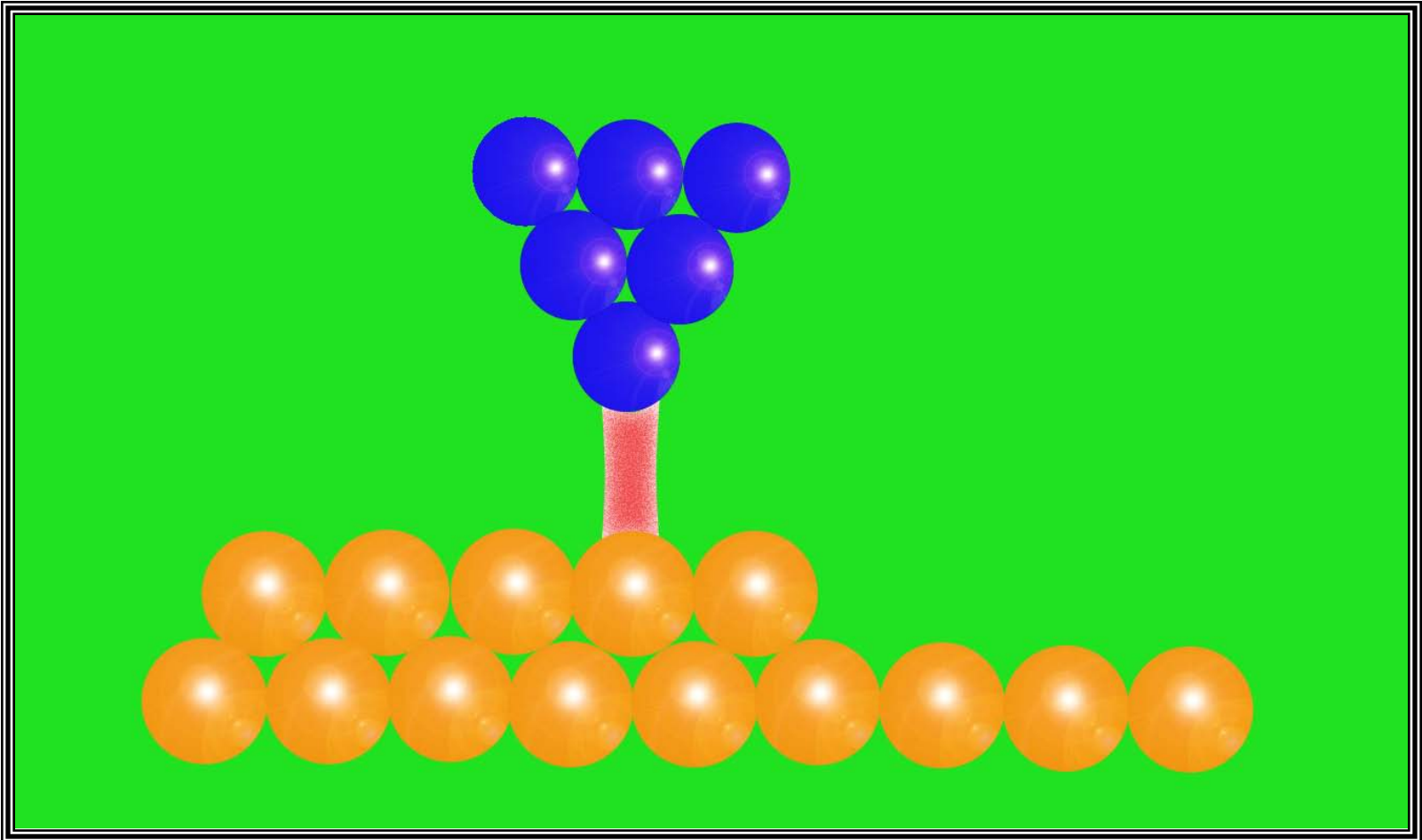
## Microscopic view of STM imaging mechanism



C.J. Chen: (1993)



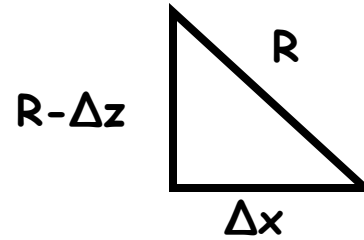
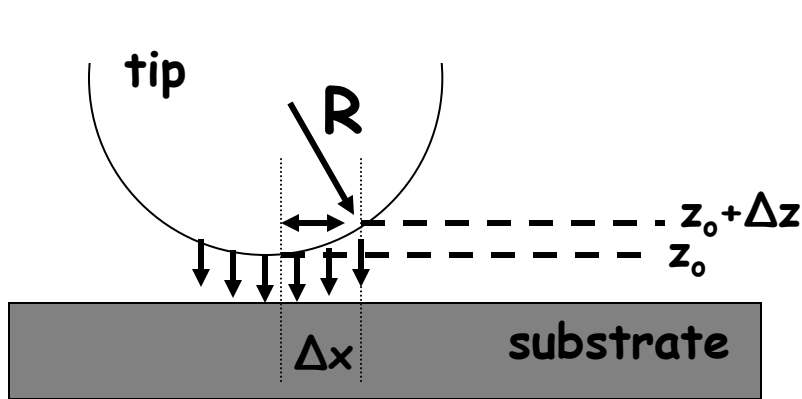
# The Front Atom IS Important



**First Law of STM: Every good tip ends in one atom**

**Second Law of STM: Reliable STM data usually requires UHV**

# Lateral Resolution?



$$R^2 = (\Delta x)^2 + (R - \Delta z)^2$$

$$\Delta z \approx \frac{(\Delta x)^2}{2R}$$

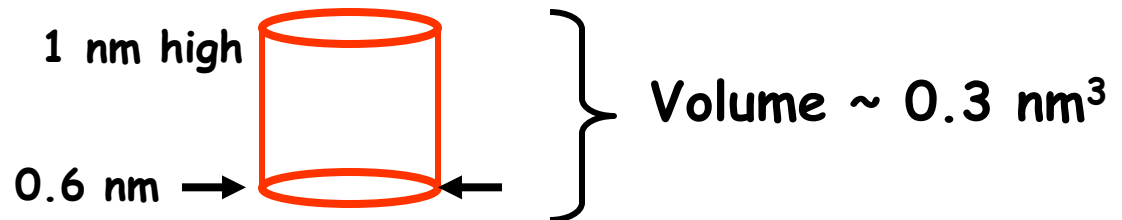
$$\alpha \approx 11 \text{ nm}^{-1}; R \approx 0.5 \text{ nm}$$

$$\text{When } e^{-2\alpha(\Delta z)} \approx 0.1 \text{ then } I \approx I_0 e^{-2\alpha(z_0 + \Delta z)} \approx 0.1 I_0 e^{-2\alpha(z_0)}$$

$$\Rightarrow \Delta x = 0.3 \text{ nm.}$$

"Effective" diameter of current column is

$\sim 2\Delta x \approx 0.6 \text{ nm} \rightarrow$  estimate for lateral resolution



How many gas molecules per  $\text{cm}^3$  at atmospheric pressure?

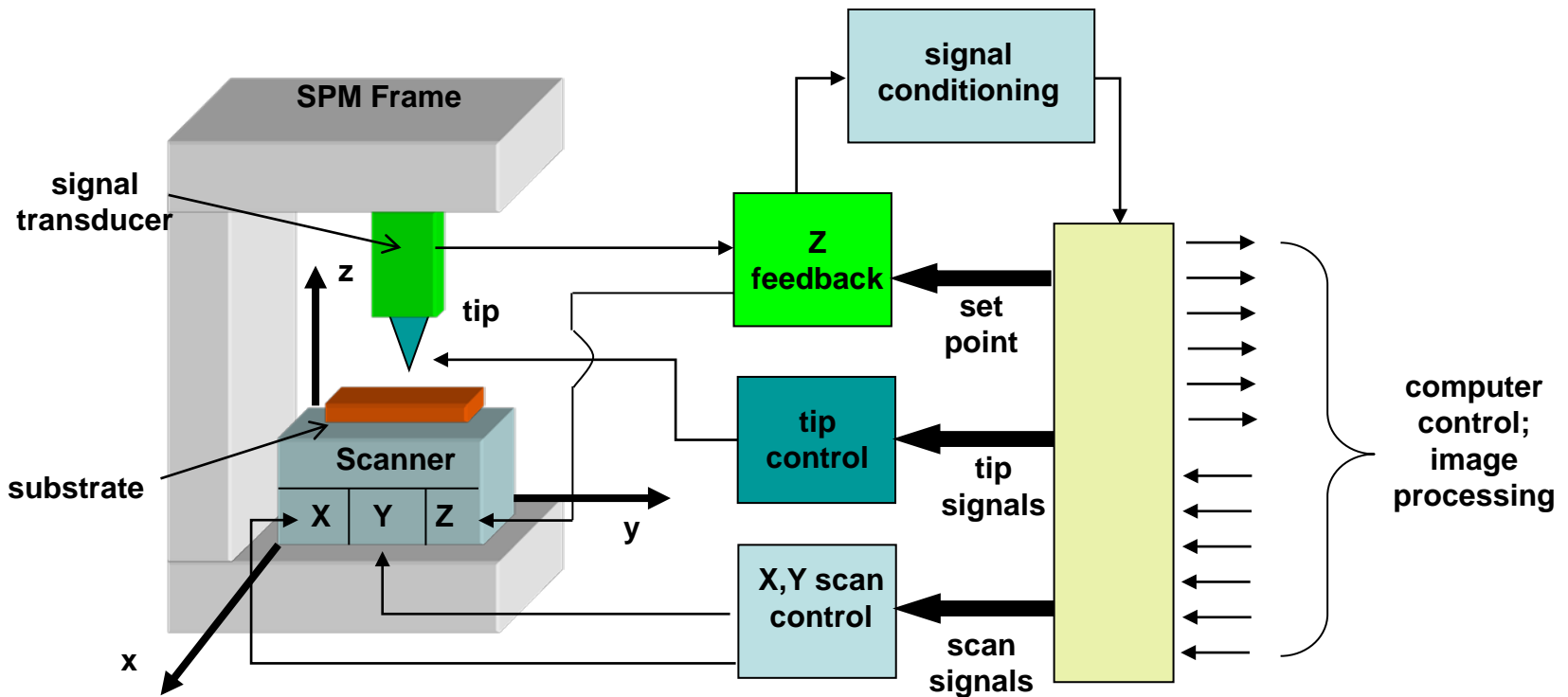
Ideal gas law:  $PV = nk_B T \rightarrow$

1 mole of gas ( $6 \times 10^{23}$  molecules) occupies 22.4 liters at STP

$$\begin{aligned} \frac{n}{V} &= \frac{P}{k_B T} = \frac{6 \times 10^{23}}{22.4 \text{ liters}} \times \frac{1 \text{ liter}}{0.001 \text{ m}^3} \times \frac{1 \text{ m}^3}{1 \times 10^6 \text{ cm}^3} \\ &= 2.7 \times 10^{19} \text{ cm}^{-3} \quad (\text{Loschmidt's Number - 1865}) \\ &= 2.7 \times 10^{19} \text{ cm}^{-3} \times \left( \frac{1 \text{ cm}}{1 \times 10^7 \text{ nm}} \right)^3 = 0.03 \text{ molecules per nm}^3 \end{aligned}$$

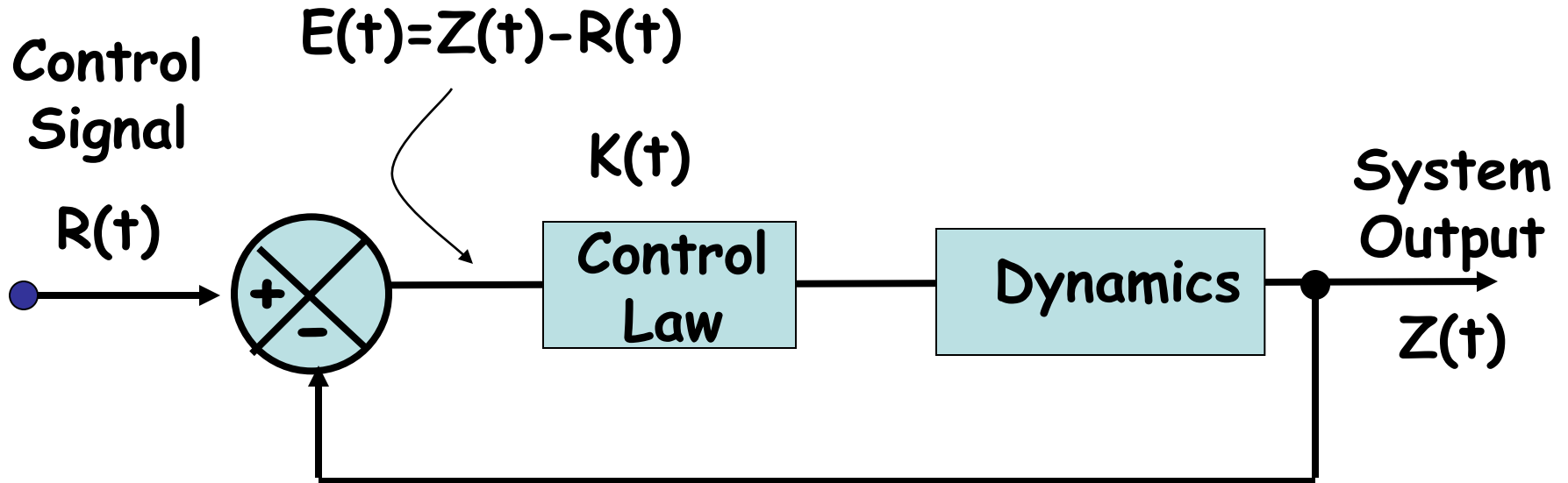
**How to make it work**

# STM System Overview



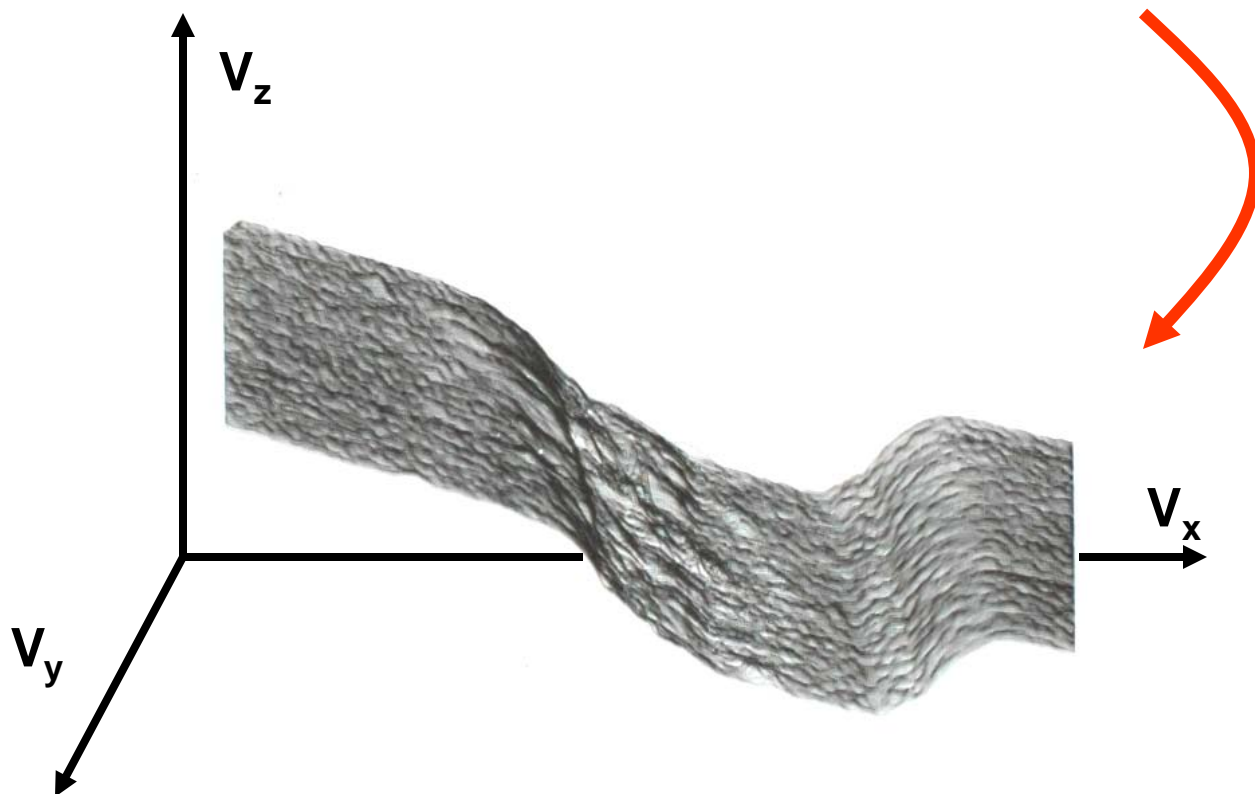
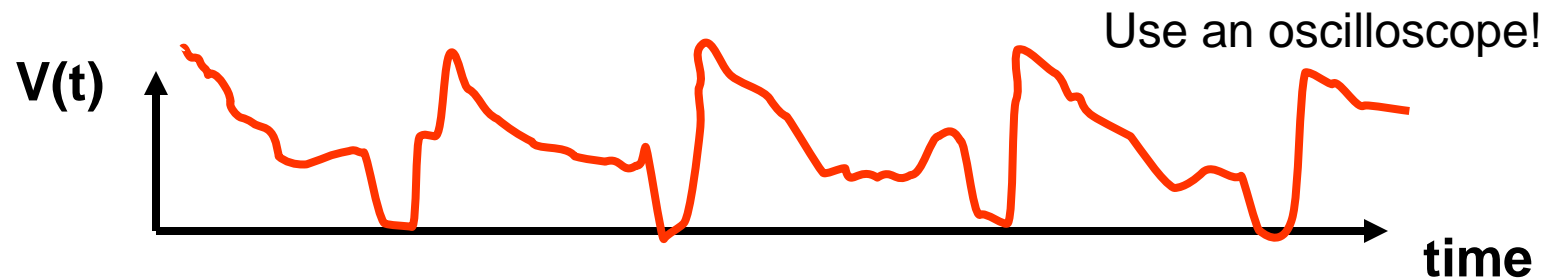
# Feedback Control

Goal: Make  $Z(t)$  follow  $R(t)$  as closely as possible



- $K(t)$  tries to minimize  $E(t)$
- Self-correcting system → negative feedback!
- A simple proportional feedback is  $Z(t) = K \cdot E(t)$

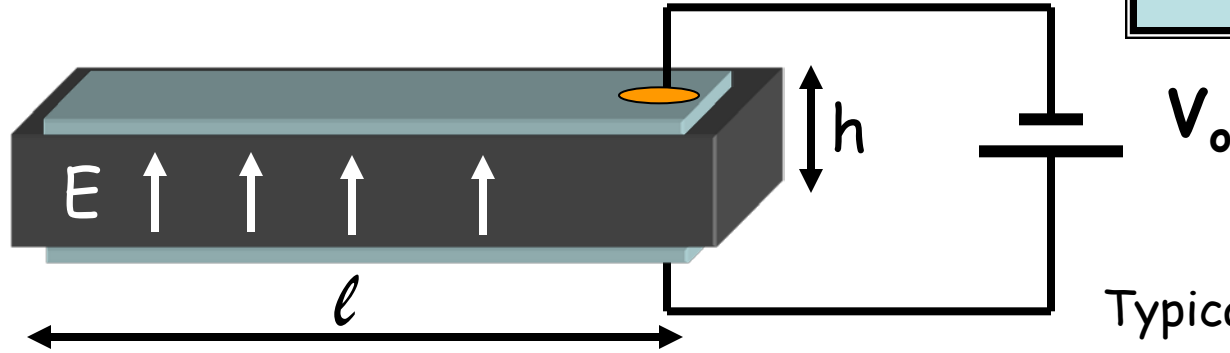
# ALL STM images are derived from voltages!



Implications for Imaging Processing

# Achieving Vibrationless Motion at the Nanoscale

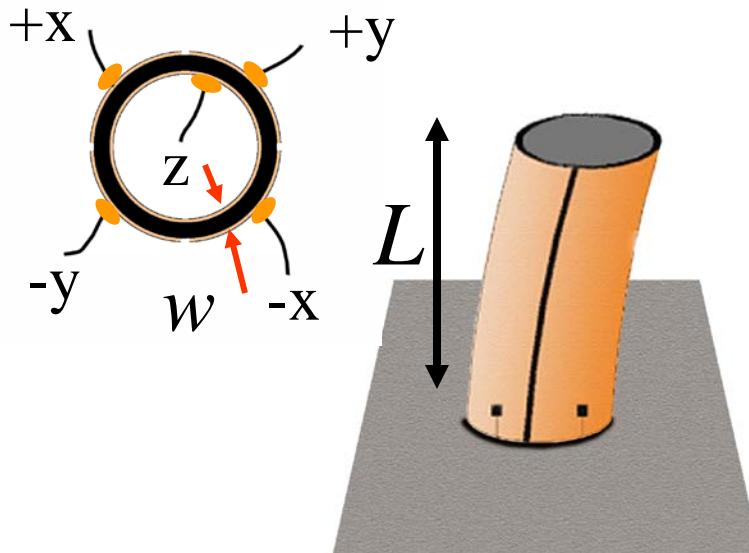
Piezoelectric Bar



$$\Delta l = d_{31} \frac{l}{h} V_o$$

Typically,  $\Delta l \sim 0.5 \text{ nm/V}$

Quadranted Piezoelectric Tube

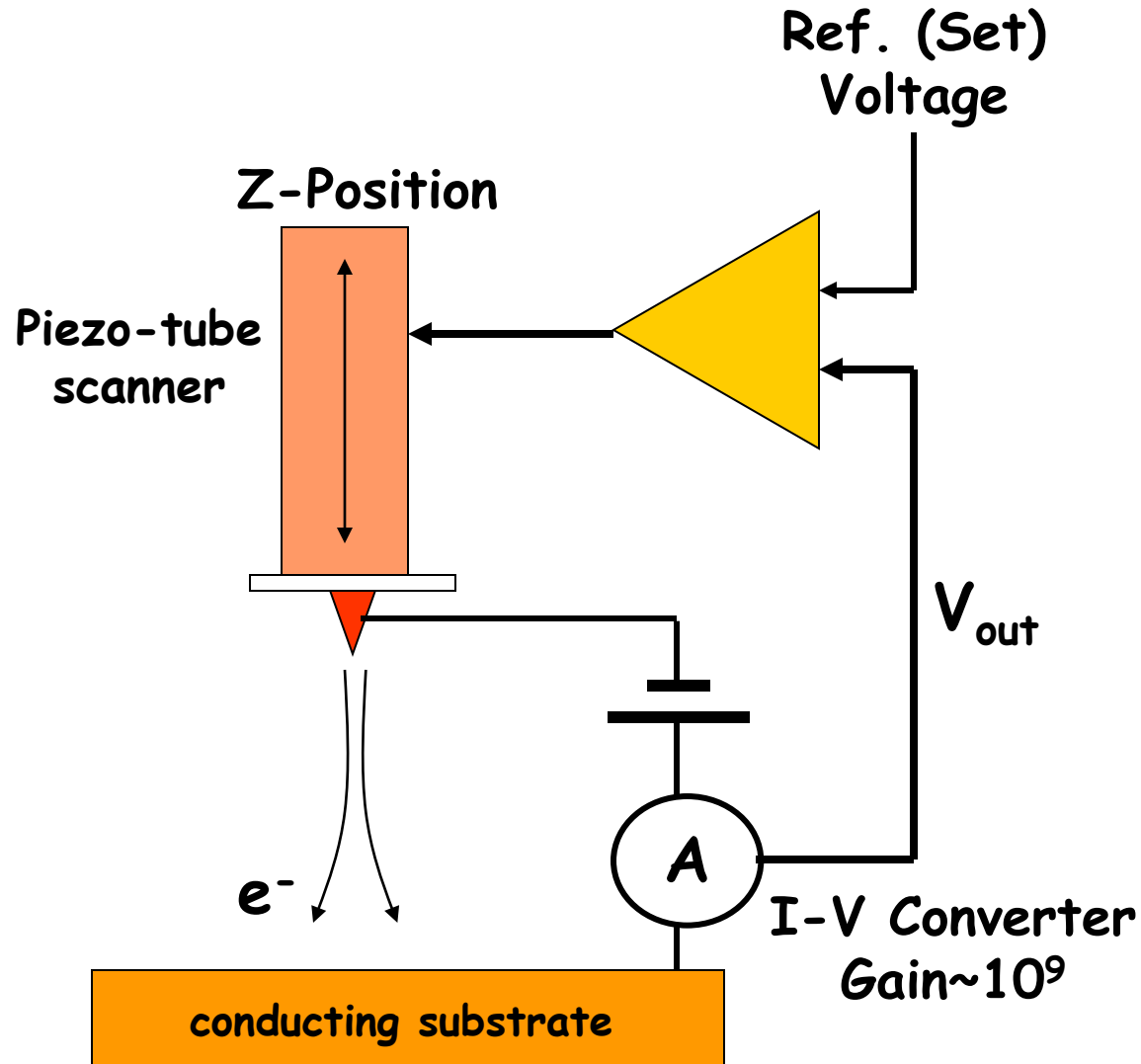


$$\Delta z = L \frac{V_o}{w} d_{31}$$

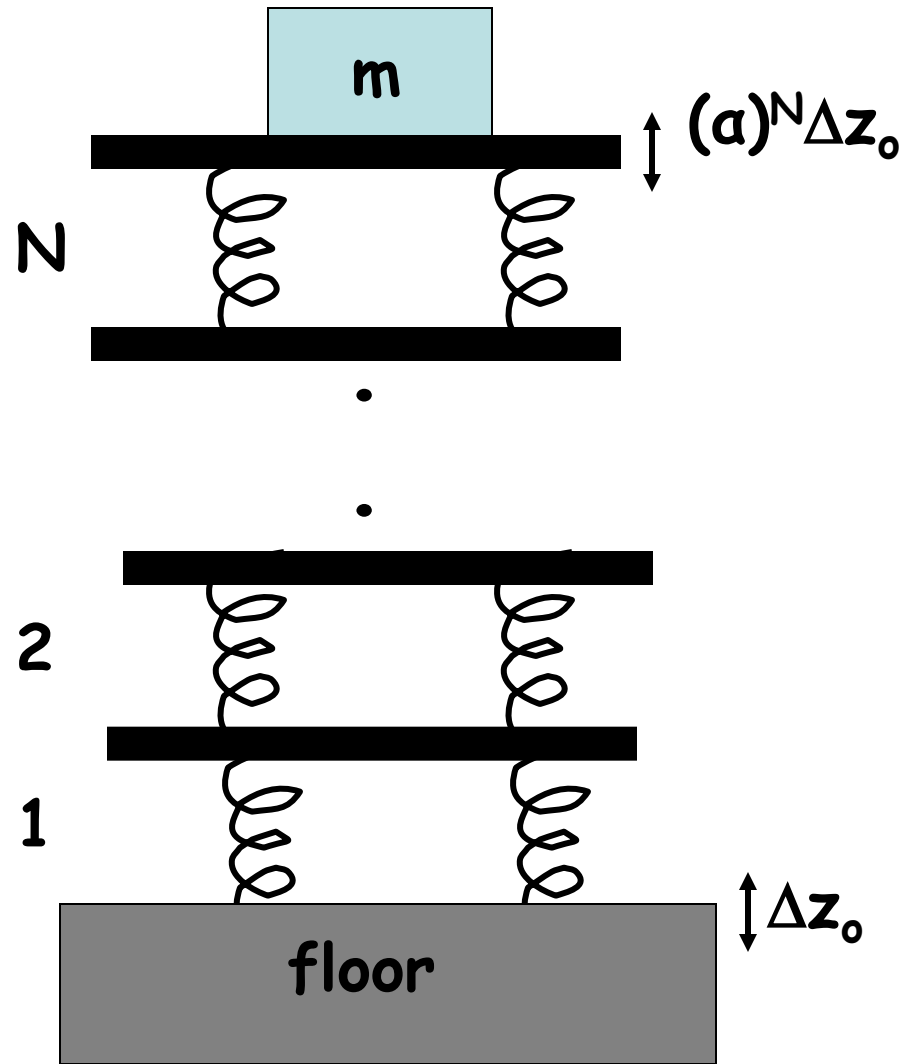
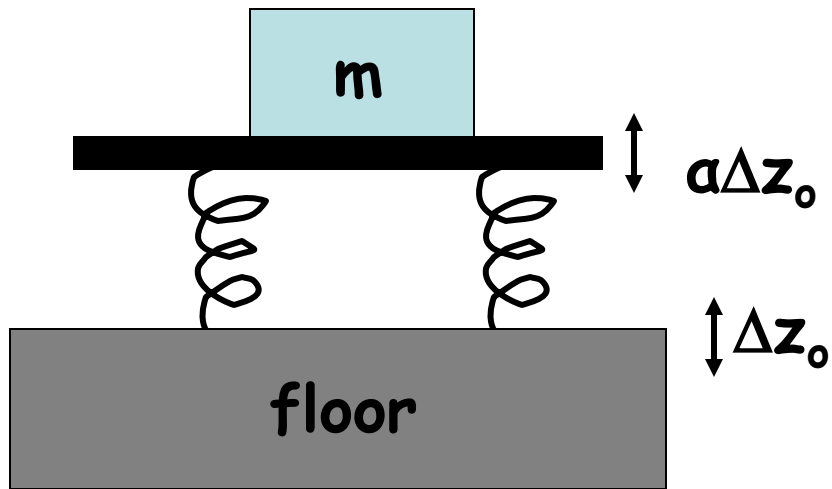
$$\Delta x \approx \Delta y = \frac{2\sqrt{2}}{\pi D} \frac{V_o}{w} L^2 d_{31}$$



# Controlling the Tunnel Gap

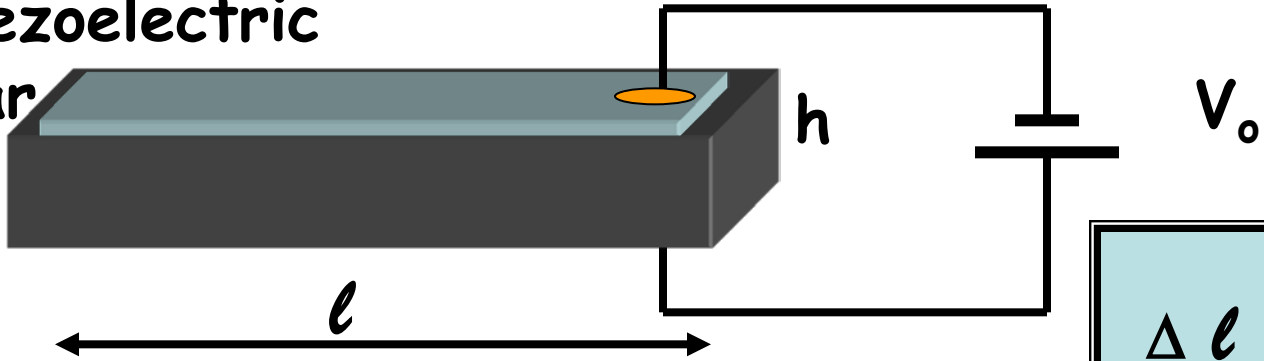


# Vibration Damping

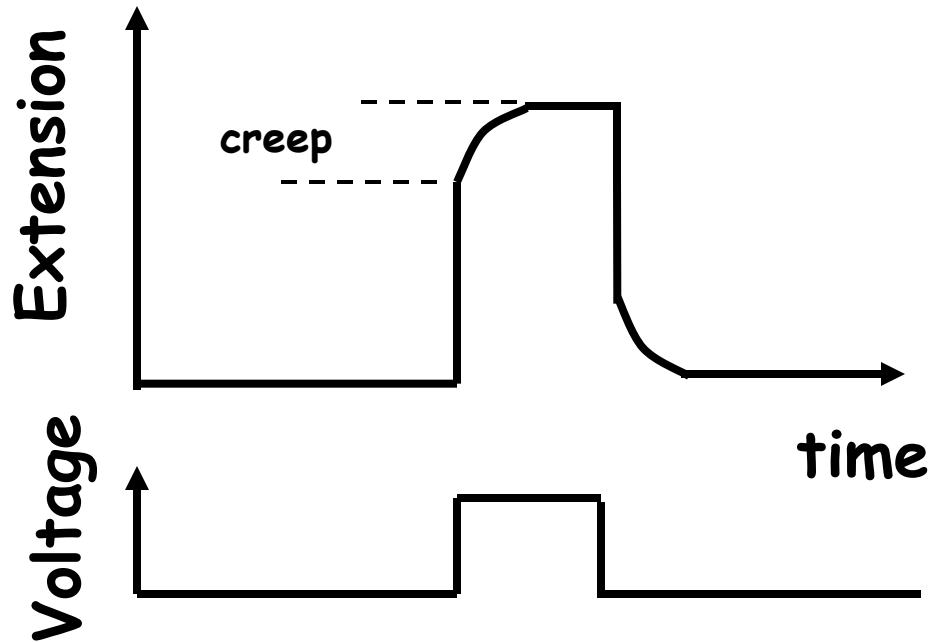


# Limitations of Piezos

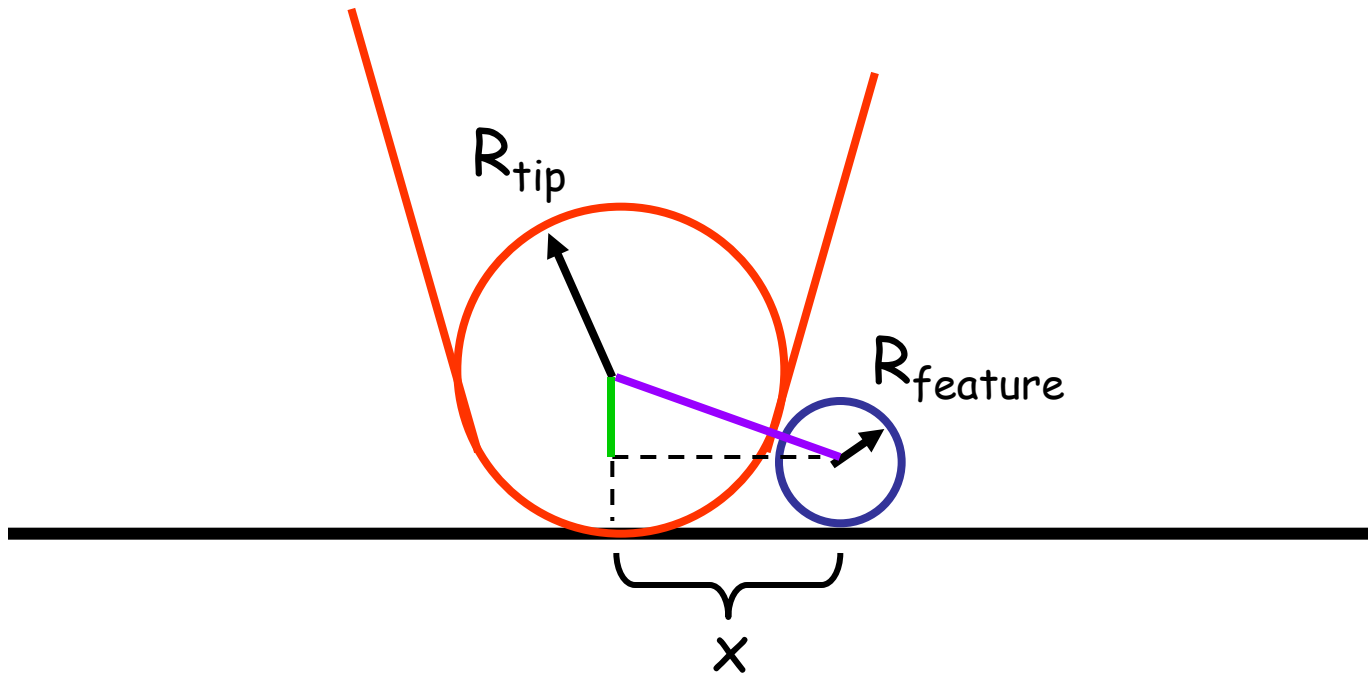
Piezoelectric  
Bar



$$\Delta l = d_{31} \frac{l}{h} V_0$$



# Apparent width of small object



$$x^2 = (R_{tip} + R_{feature})^2 - (R_{tip} - R_{feature})^2$$

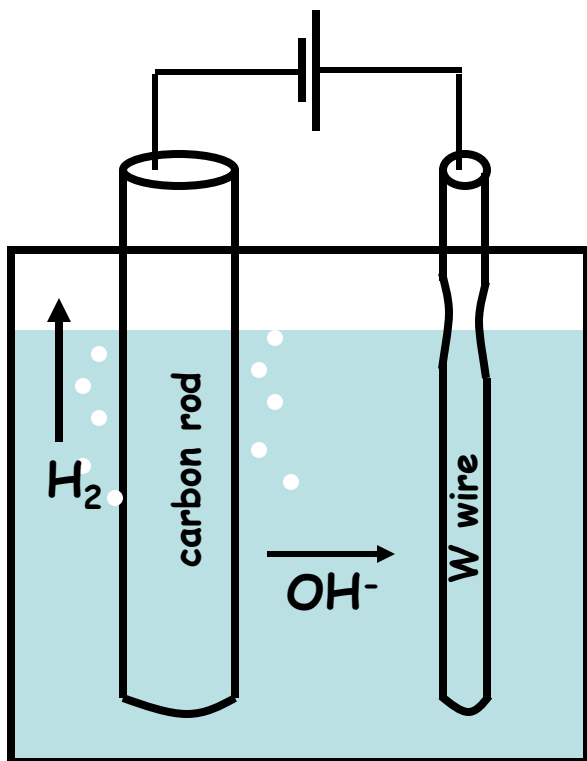
$$x^2 = \cancel{R_{tip}^2} + 2R_{tip}R_{feature} + \cancel{R_{feature}^2} - \cancel{R_{tip}^2} + 2R_{tip}R_{feature} - \cancel{R_{feature}^2}$$

$$x = 2\sqrt{R_{tip}R_{feature}}$$

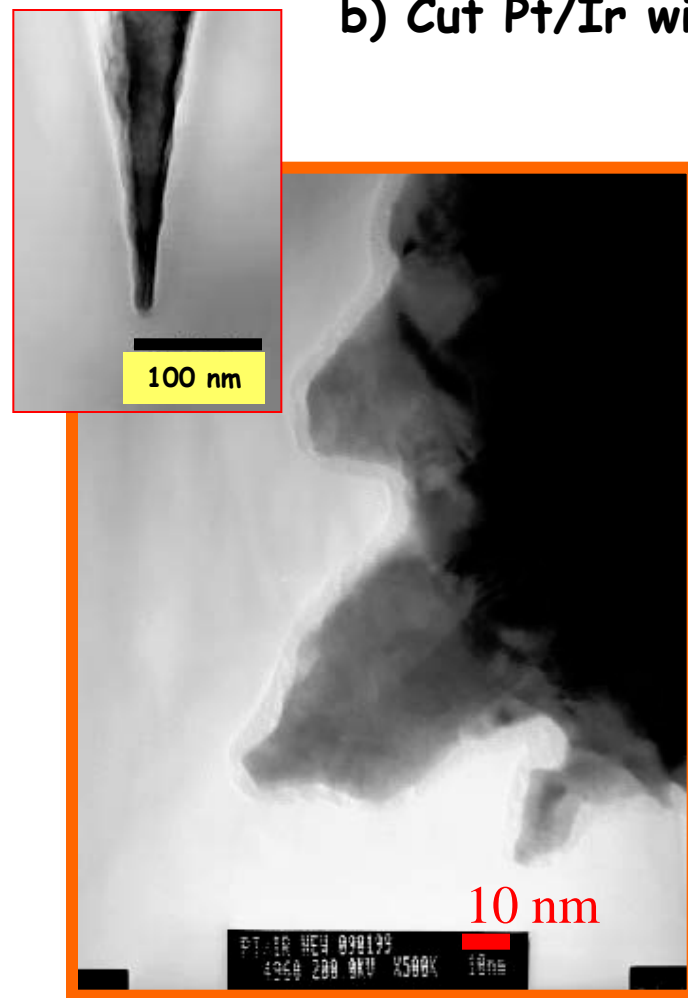
$$\text{apparent feature width} \approx 2x = 4\sqrt{R_{tip}R_{feature}}$$

# Tip Fabrication

a) Electrochemical etch of W wire



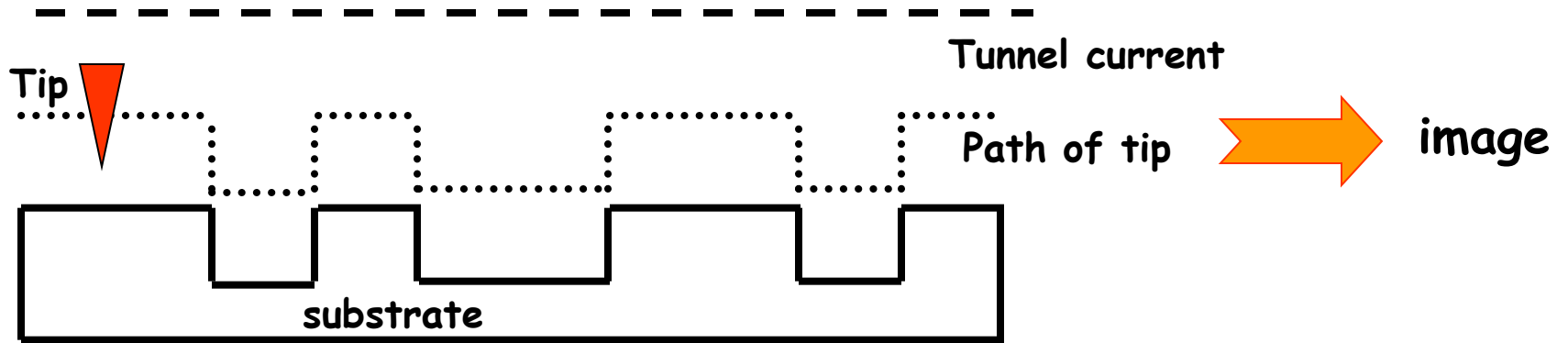
b) Cut Pt/Ir wire



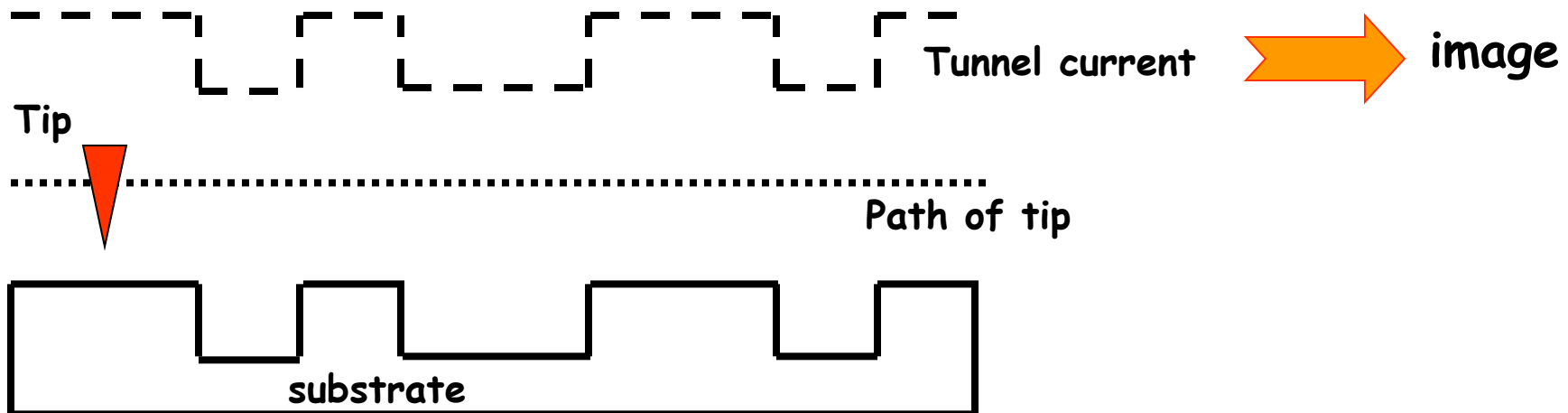
STM tip  
(~ 75 exterior atoms)

# Scanning Modes

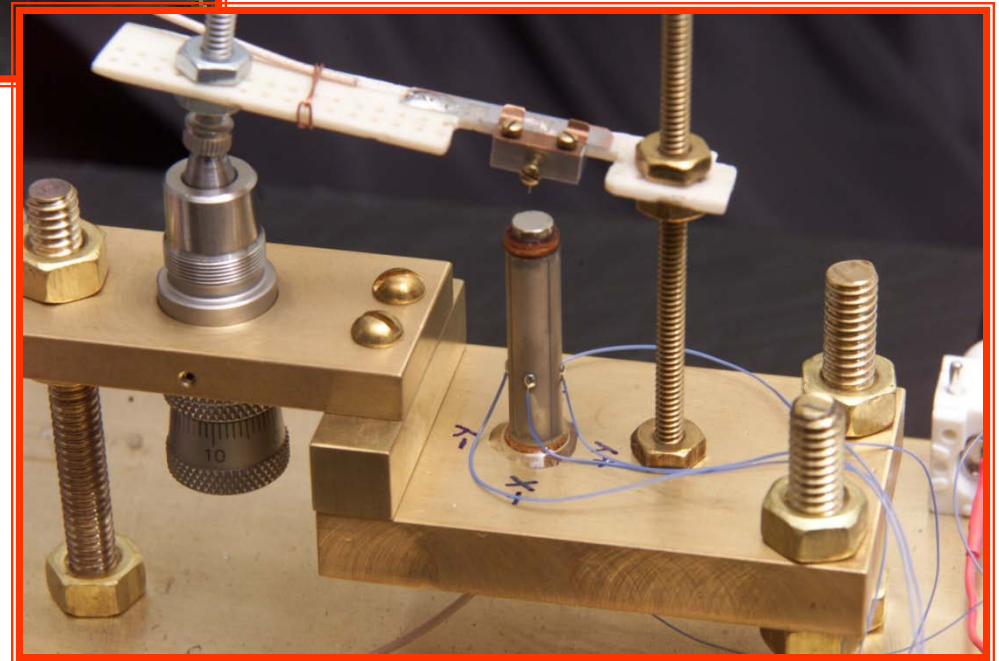
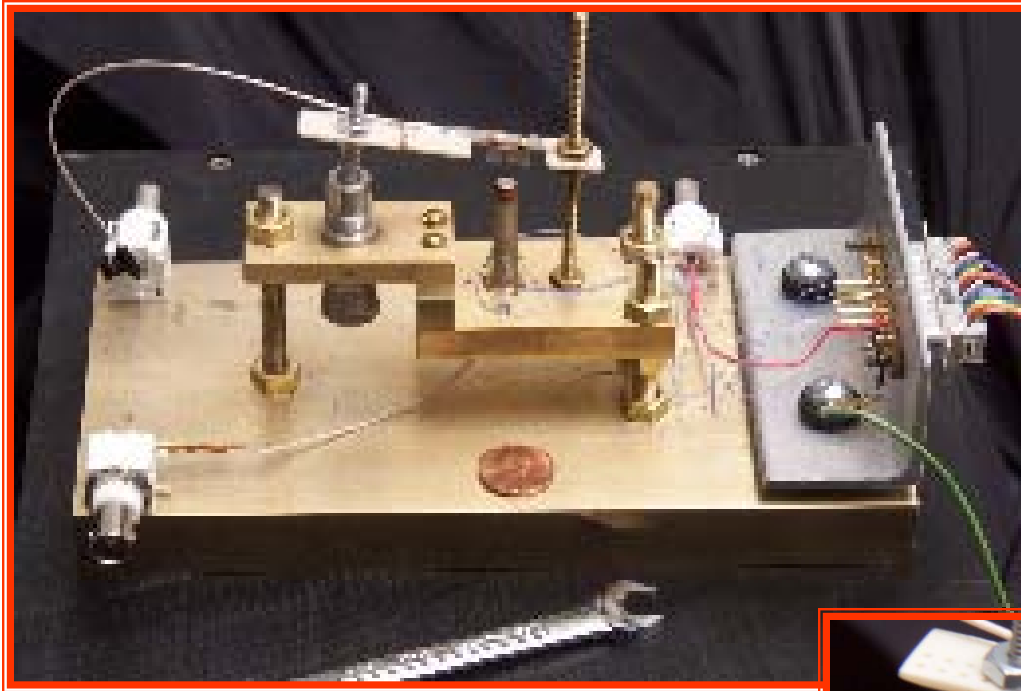
## Constant Current → Topography



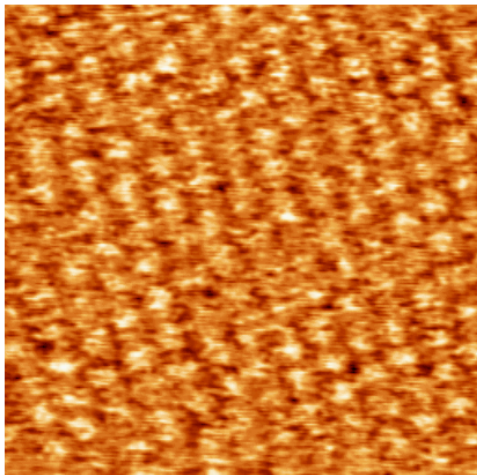
## Constant Height → High Speed



# Seeing atoms in a day



Highly oriented pyrolytic graphite (HOPG)



4.8 nm  $\times$  4.8 nm

# A Forerunner of STM - The Topographiner

In 1971 Russell Young and co-workers demonstrated a **noncontact** stylus profiler called a Topographiner.

Relies on the **field emission current** between a sharp metal tip and a conducting surface as a sensitive measure of the tip-sample distance.

Probe tip mounted directly on a piezoelectric ceramic

Electronic feedback circuit

Probe scans the surface in the horizontal (X-Y) dimensions using piezoelectric ceramics

